

SANYO Semiconductors DATA SHEET

2SA1469 / 2SC3746 — FNP / NPN Epitaxial Planar Silicon Transistors 60V / 5A High-Speed Switching Applications

Applications

- · Various inductance lamp drivers for electrical equipment.
- · Inverters, converters (flash, fluorescent lamp lighting circuit).
- · Power amp (high power car stereo, motor controller).
- · High-speed switching (switching regulator, driver).

Features

- · Low saturation voltage.
- · Excellent current dependence of hFE.
- · Short switching time.
- · Micaless package facilitating mounting.

Specifications (): 2SA1469

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		(-)80	V
Collector-to-Emitter Voltage	VCEO		(-)60	V
Emitter-to-Base Voltage	VEBO		(-)5	V
Collector Current	IC		(-)5	Α
Collector Current (Pulse)	ICP		(-)7	Α
Collector Dissipation	Do		2	W
	PC	Tc=25°C	20	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Llait
Farameter	Symbol		min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =(-)40V, I _E =0A			(-)0.1	mA
Emitter Cutoff Current	IEBO	V _{EB} =(-)4V, I _C =0A			(-)0.1	mA
DC Current Gain	hFE	VCE=(-)2V, IC=(-)1A	70*		280*	

^{*:} The 2SA1469/2SC3746 are classified by 1A hFE as follows:

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Rank	Q	R	S
hFE	70 to 140	100 to 200	140 to 280

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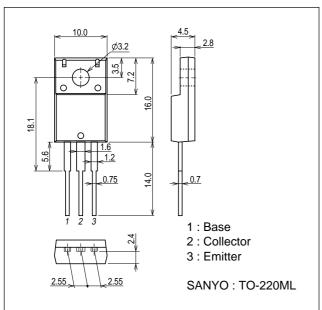
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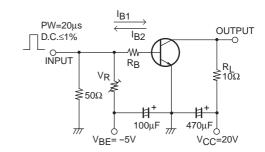
Parameter	Symbol	Conditions	Ratings			Unit
Falanielei	Symbol		min	typ	max	Offic
Gain-Bandwidth Product	fT	VCE=(-)5V, IC=(-)1A		100		MHz
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	I _C =(-)2.5A, I _B =(-)0.125A			(-)0.4	٧
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=(-)1mA, IE=0A	(-)80			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=(-)1mA, RBE=∞	(-)60			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =(-)1mA, I _C =0A	(-)5			٧
Turn-On Time	ton	See specified Test Circuit.		0.1		μs
Storage Time	tstg	See specified Test Circuit.		0.5		μs
Fall Time	tf	See specified Test Circuit.		0.1		μs

Package Dimensions

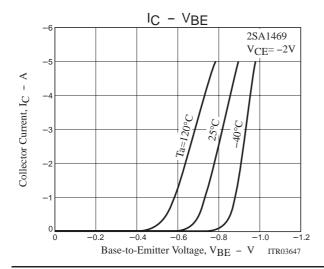
unit : mm (typ) 7508-002

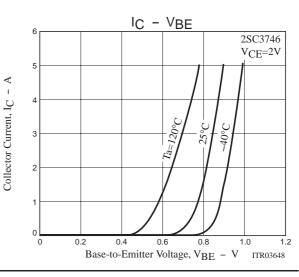


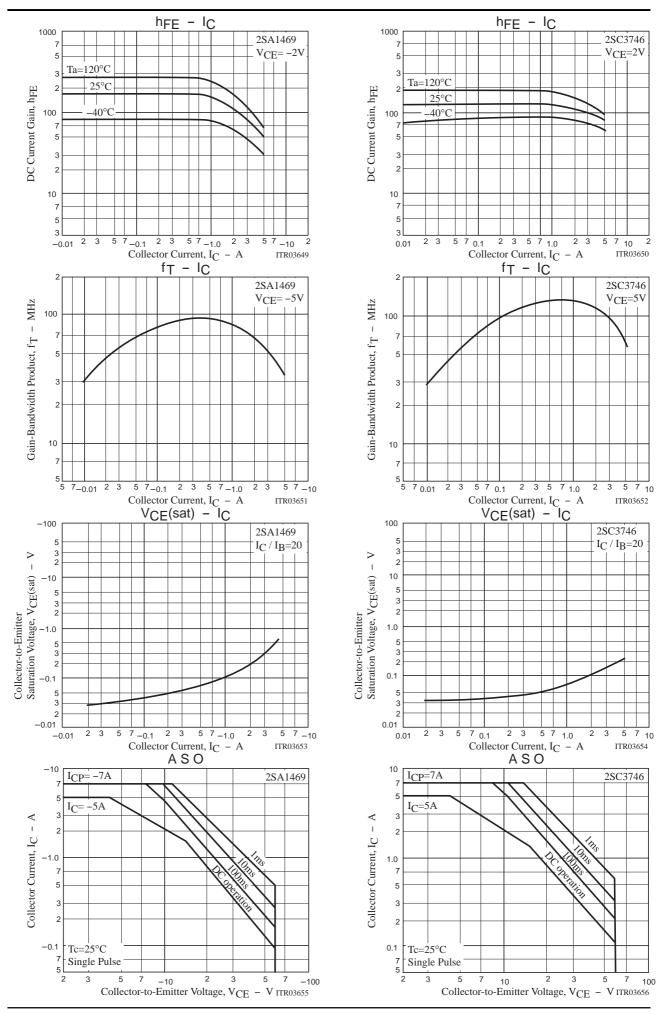
Switching Time Test Circuit



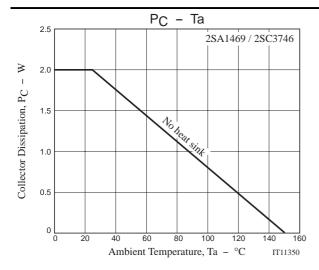
 $20I_{B1} = -20I_{B2} = I_C = 2A$ For PNP, the polarity is reversed.

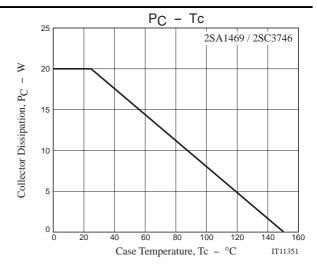






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